



FOR IMMEDIATE RELEASE

MEDIA ALERT

**Everspin to Showcase Partnerships Leveraging 1Gb STT-MRAM
and Deliver Eight Industry Presentations at Flash Memory
Summit 2019**

Everspin's groundbreaking and proven technology enables enterprise infrastructure and data center providers to increase their reliability and performance

SANTA CLARA, Calif., Aug 1, 2019 – [Everspin Technologies, Inc.](http://www.everspin.com), (NASDAQ: MRAM), the world's leading developer and manufacturer of Magnetoresistive RAM (MRAM) persistent memory solutions, will exhibit and present at MRAM Developer Day on Monday, August 5 and Flash Memory Summit through Thursday, August 8 in Santa Clara, CA.

WHO: Everspin Technologies

WHAT: MRAM Developer Day and Flash Memory Summit 2019

Everspin Presentations (papers available on request):

MRAM Developer Day Keynote, The MRAM Revolution. Kevin Conley, President & CEO, Everspin. MRAM is advancing towards the promise of true universal persistent memory, delivering the benefit of persistence with the performance and endurance needed for memory workloads. **Monday, August 5, 9:15 a.m.**

MRAM Application Brief. Using MRAM to Enable Power Loss Protection for NVMe. **Monday, August 5, 2:00 p.m., Track #1 Ballroom**

Persistent Memory Part 1: Advances in Persistent Memory. As NAND Flash based storage systems evolve to higher densities, managing I/O determinism has become a challenge. **Tuesday, August 6, 8:30 a.m. Ballroom E.**

Nonvolatile Memory Technology in China Today. Exploring the application and usage models of Nonvolatile Memory Technology in China Today. **Tuesday, August 6, 3:40 p.m., Ballroom G.**

Enterprise SSDs - Designing SSD Storage Systems for Low Latency Without Large Outliers. Co-presented with Phison. Applications such as



financial transactions, large inventory management, and social media networks, require extremely low latency without significant outliers. That is, they want to keep so-called tail latency low, avoiding occasional long delays that cascade throughout the system. **Tuesday, August 6, 3:40 p.m., Ballroom F.**

FMS Chat with the Experts (Free pizza and beer!). Will allow you to meet one-on-one with a large number of experts within the flash memory industry. MRAM table staffed by Everspin. **Tues, August 6, 7:00-8:30 p.m., on site.**

MRAM. Flash memory is limited by performance such as data-access-speed, bit-access, and data retention. In this presentation, we will review competing alternate technologies that are being explored. **Wednesday, August 7, 4:35 p.m., Ballroom G.**

Demystifying NVMe over Fabrics. A new generation of networking devices over 25Gb speeds have made big advancements from the past. **Thursday, August 8, 8:30 a.m., Great America Ballroom J.**

What's the Best Approach to Persistent Memory Today...and Tomorrow? Panel discussion on implementing Persistent Memory across a variety of applications. **Thursday, August 8, 2:10 p.m., Great America Meeting Room 2.**

WHEN: Monday, August 5 – Thursday, August 8, 2019

WHERE: **Everspin Booth #319**
Santa Clara Convention Center
5001 Great America Pkwy
Santa Clara, CA

THE STORY: In advance of MRAM Developer Day and Flash Memory Summit, Everspin is announcing partnerships with three companies leveraging Everspin's groundbreaking 1 Gb STT-MRAM to improve reliability and performance. As the world's leading developer and manufacturer of MRAM, Everspin is the only company delivering an unprecedented combination of persistence and high endurance non-volatile memory for applications demanding high bandwidth, low-latency and reliable performance. The partners to be announced and Everspin will be available to discuss their particular applications.

RESOURCES: Company website – <https://www.everspin.com/our-company>



STT-MRAM – <https://www.everspin.com/spin-transfer-torque-mram-technology>

Technical papers – <https://www.everspin.com/technical-papers>

1 Gb STT-MRAM announcement –

<https://www.everspin.com/news/everspin-enters-pilot-production-phase-world%E2%80%99s-first-28-nm-1-gb-stt-mram-component>

MRAM Developer Day website –

https://www.mramdeveloperday.com/English/Conference/Conference_Info.html

Flash Memory Summit website – <https://www.flashmemorysummit.com/>

About Everspin Technologies

Everspin Technologies, Inc. is the world's leading provider of Magnetoresistive RAM (MRAM), delivering unprecedented performance, non-volatility, endurance and reliability for applications where data persistence is paramount. Headquartered in Chandler, Arizona, Everspin is transforming the memory market with the largest and most diverse foundation of MRAM customers. For more information, visit www.everspin.com. NASDAQ: MRAM.

Cautionary Statement Regarding Forward-Looking Statements

This press release contains forward-looking statements regarding future events that involve risks and uncertainties that could cause actual results or events to differ materially from the expectations disclosed in the forward-looking statement, including, but not limited to; the anticipated market adoption of Everspin's products and technology at the rate Everspin expects; the ability for Everspin to expand the markets Everspin addresses at the rate it expects; the risk that unexpected technical difficulties may develop in the final stages of development or production of its products, or when Everspin's customers may ship in volume. Readers are advised that they should not place undue reliance on these forward-looking statements and should review the risk factors included in Everspin's Form 10-Q filed with the Securities and Exchange Commission on May 9, 2019, under the caption "Risk Factors." Subsequent events may cause these expectations to change, and Everspin disclaims any obligations to update or alter these forward-looking statements in the future, whether as a result of new information, future events or otherwise.

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